TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX16240AFT

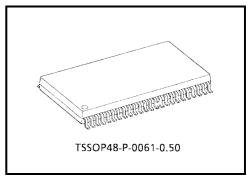
Low-Voltage 16-Bit Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCX16240AFT is a high-performance CMOS 16-bit bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage $(3.3~\rm{V})~\rm{VCC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This device is inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the $\overline{\rm OE}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

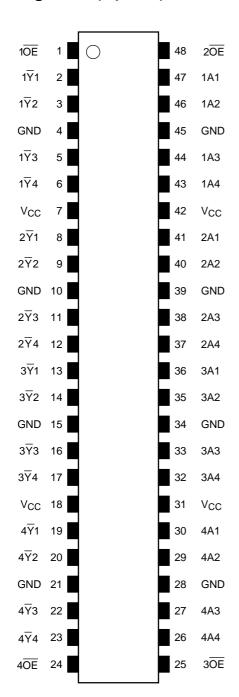


Weight: 0.25 g (typ.)

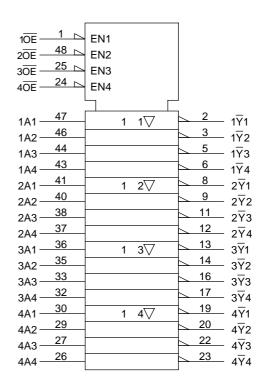
Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 4.9 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: TSSOP (thin shrink small outline package)
- Power-down protection provided on all inputs and outputs

Pin Assignment (top view)



IEC Logic Symbol



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Truth Table

Inp	uts	Outputs
1 OE	1A1-1A4	1 <u>Y</u> 1 - 1 <u>Y</u> 4
L	L	Н
L	Н	L
Н	X	Z

Inp	uts	Outputs
2 OE	2A1-2A4	2 Y 1 - 2 Y 4
L	L	Н
L	Н	L
Н	X	Z

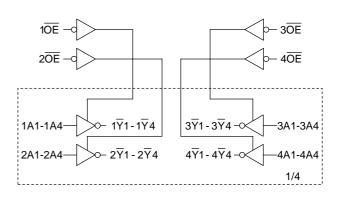
Inp	uts	Outputs
3 OE	3A1-3A4	3 <u>Y</u> 1 - 3 <u>Y</u> 4
L	L	Н
L	Н	L
Н	Х	Z

Inp	uts	Outputs
4 OE	4A1-4A4	4 <u>Y</u> 1 - 4 <u>Y</u> 4
L	L	Н
L	Н	L
Н	Х	Z

X: Don't care

Z: High impedance

System Diagram



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Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
Input voltage	V_{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 2)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 3)	mA
DC output current	I _{OUT}	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Output in OFF state

Note 2: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
Power supply voltage	vCC	1.5 to 3.6 (Note 4)	V	
Input voltage	V _{IN}	0 to 5.5	٧	
Output voltage	V _{OUT}	0 to 5.5 (Note 5)	V	
Output voltage		0 to V _{CC} (Note 6)		
Output current	1 /1	±24 (Note 7)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 8)	ША	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V	

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 8: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characterist	ics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
	H-level	V _{IH}	_		2.7 to 3.6	2.0	_	
Input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	0.8	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} -0.2	_	
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
				I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	V/	Var. Var. or Va	I _{OL} = 12 mA	2.7	_	0.4	
	L-ievei	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current	•	I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
3-state output OFF sta	ate current	loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μА
Power-off leakage cur	rent	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Ouissant supply sure	- n+		V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	
Quiescent supply curre	51 IL	Icc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±20.0	μΑ
Increase in Icc per inp	ut	Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500	



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Drangation delay time	t _{pLH}	Figure 4 Figure 2	2.7	_	5.9	20
Propagation delay time	t _{pHL}	Figure 1, Figure 2	3.3 ± 0.3	1.5	4.9	ns
3-state output enable time	t _{pZL}	Figure 4 Figure 2	2.7	_	7.5	ns
5-State output enable time	Figure 1, Figure 3	3.3 ± 0.3	1.5	6.5	110	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	6.5	ns
5-state output disable time	t _{pHZ}	rigure 1, rigure 3	3.3 ± 0.3	1.5	5.5	2
Output to output skew	t _{osLH}	(Note 10)	2.7	_		ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	10

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		3.3	7	pF
Output capacitance	C _{OUT}	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note 11)	3.3	25	pF

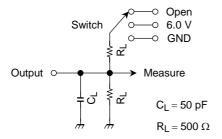
Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

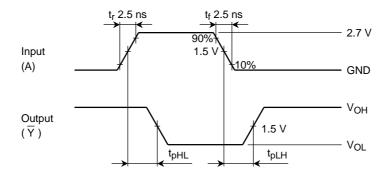


Figure 2 t_{pLH}, t_{pHL}

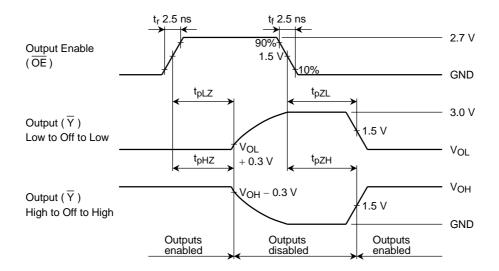
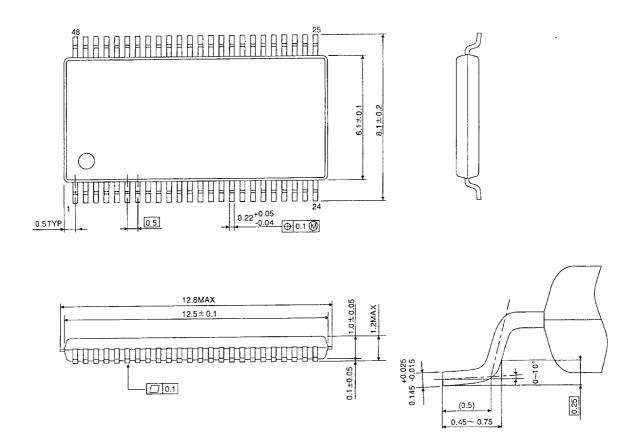


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Package Dimensions

TSSOP48-P-0061-0.50 Unit: mm



Weight: 0.25 g (typ.)

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